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SERIAL NUMBER 10/510,695	FILING OR 371(c) DATE 10/08/2004 RULE	CLASS 117	GROUP ART UNIT 1765	ATTORNEY DOCKET NO. 121356
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APPLICANTS

Izumi Fusegawa, Fukushima, JAPAN;
 Sadayuki Okuni, Fukushima, JAPAN;
 Nobuaki Mitamura, Fukushima, JAPAN;
 Tomohiko Ohta, Fukushima, JAPAN;
 Nobuo Katuoka, Fukushima, JAPAN;

** CONTINUING DATA *****

This application is a 371 of PCT/JP03/05167 04/23/2003

** FOREIGN APPLICATIONS *****

JAPAN 2002-122250 04/24/2002

Foreign Priority claimed	<input type="checkbox"/> yes <input type="checkbox"/> no	STATE OR COUNTRY JAPAN	SHEETS DRAWING 3	TOTAL CLAIMS 9	INDEPENDENT CLAIMS 3
35 USC 119 (a-d) conditions met	<input type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after Allowance				
Verified and Acknowledged	Examiner's Signature _____ Initials _____				

ADDRESS

25944

TITLE

Method for producing silicon single crystal and, silicon single crystal and silicon wafer

FILING FEE RECEIVED 950	FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT No. _____ for following:	<input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees (Filing) <input type="checkbox"/> 1.17 Fees (Processing Ext. of time) <input type="checkbox"/> 1.18 Fees (Issue) <input type="checkbox"/> Other _____ <input type="checkbox"/> Credit
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